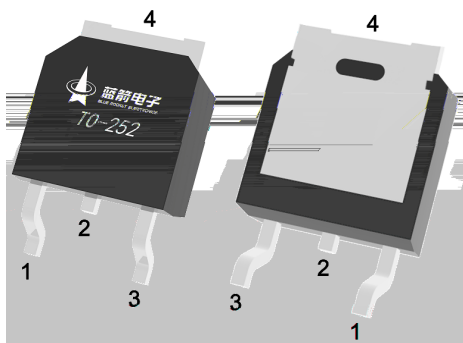
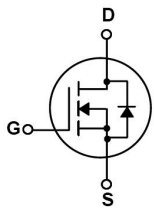


TO-252          N      MOS  
N-CHANNEL MOSFET in a TO-252 Plastic Package.

$V_{DS}(V) = 20V$      $I_D=65A(V_{GS}=\pm 12V)$   
 $R_{DS(ON)}@4.5V$  8m (Typ. 5m )  
 $R_{DS(ON)}@2.5V$  10m (Typ. 6.2m )  
 HF Product.

DC/DC

These devices are well suited for high efficiency switching DC/DC converters and switch mode power supplies.



PIN 1 G          PIN 2 D          PIN 3 S          PIN 4 D

See Marking Instructions.

Parameter		Symbol	Rating	Unit
Drain-Source Voltage		$V_{DSS}$	20	V
Drain Current		$I_D(T_C=25^\circ\text{C})$	65	A
Peak Drain Current		$I_{DM}$	157	A
Gate-Source Voltage		$V_{GSS}$	12	V
Avalanche Current		$I_{AS}$	19	A
Single Pulsed Avalanche Energy		$E_{AS}$	361	mJ
Total Power Dissipation		$P_D(T_C=25^\circ\text{C})$	52	W
Junction and Storage Temperature Range		$T_J, T_{STG}$	-55 to 150	
Thermal resistance, junction - ambient	t = 10s	$R_{JA}$	20	/W
	Steady-State		50	
Thermal resistance, junction - case	Steady-State	$R_{JC}$	1.55	

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Zero Gate Voltage Drain Current	$BV_{DSS}$	$V_{GS}=0V$ $I_D=250\mu A$	20	24		V
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=20V$ $V_{GS}=0V$			1	$\mu A$
Gate-Body Leakage Current Forward	$I_{GSS}$	$V_{GS}=\pm 12V$ $V_{DS}=0V$			$\pm 0.1$	$\mu A$
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ $I_D=250\mu A$	0.5	0.6	1.1	V
Forward On Voltage	$V_{SD}$	$I_S=1A$ $V_{GS}=0V$			1.2	V
Static Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=4.5V$ $I_D=10A$		5	8	m
		$V_{GS}=2.5V$ $I_D=10A$		6.2	10	m
Gate resistance	$R_g$	$V_{GS}=0V$ $V_{DS}=0V$ $f=1MHz$		2		
Input Capacitance	$C_{iss}$	$V_{GS}=0V$ $V_{DS}=15V$ $f=1.0MHz$		2000		pF
Output Capacitance	$C_{oss}$			170		pF
Reverse Transfer Capacitance	$C_{rss}$			160		pF

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Total Gate Charge	$Q_g$	$V_{GS}=4.5V, V_{DS}=10V, I_D=18A$		14.7		nC
Gate Source Charge	$Q_{gs}$			1.9		
Gate Drain Charge	$Q_{gd}$			4.7		
Turn-On Delay Time	$t_{d(on)}$	$V_{GS}=4.5V, V_{DS}=10V, R_L=0.75, R_{GEN}=3$		13		ns
Turn-On Rise Time	$t_r$			23		ns
Turn-Off Delay Time	$t_{d(off)}$			60		ns
Turn-Off Fall Time	$t_f$			35		ns

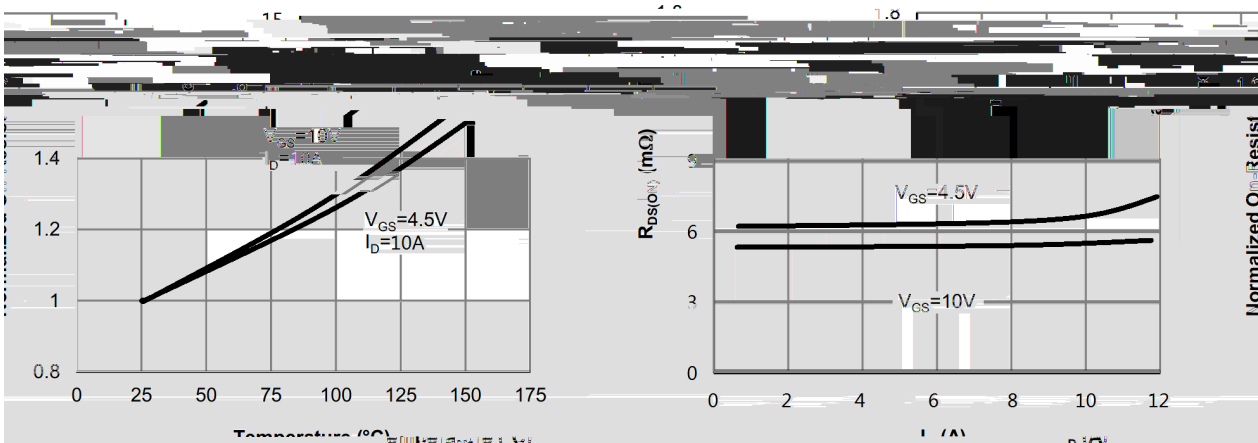
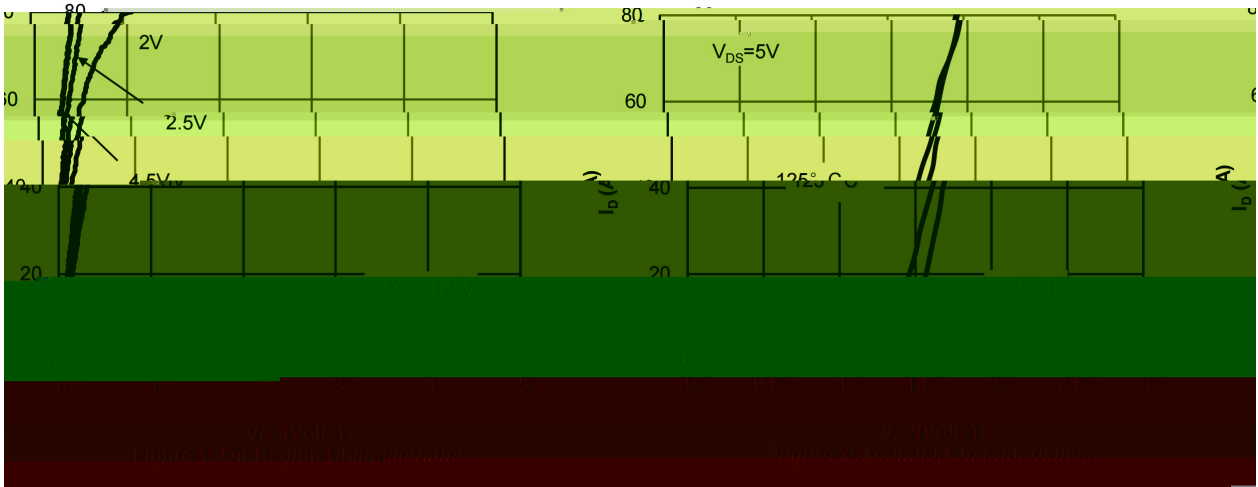
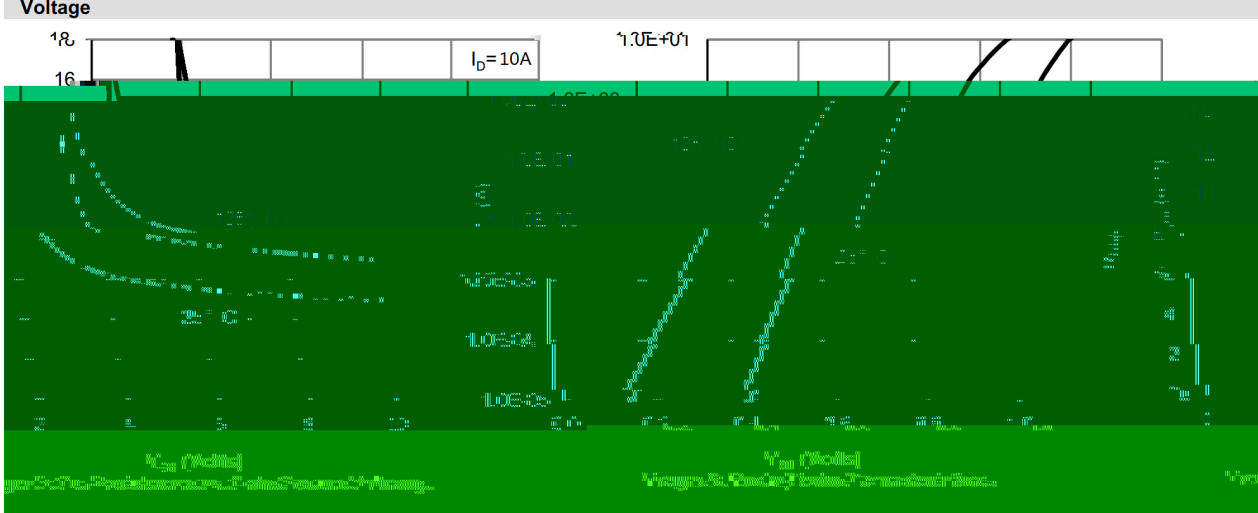
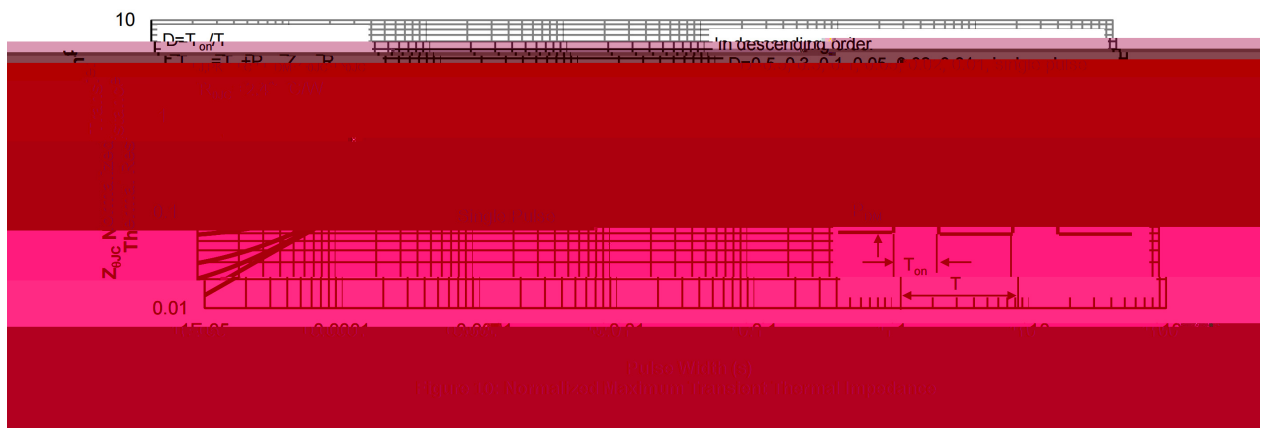
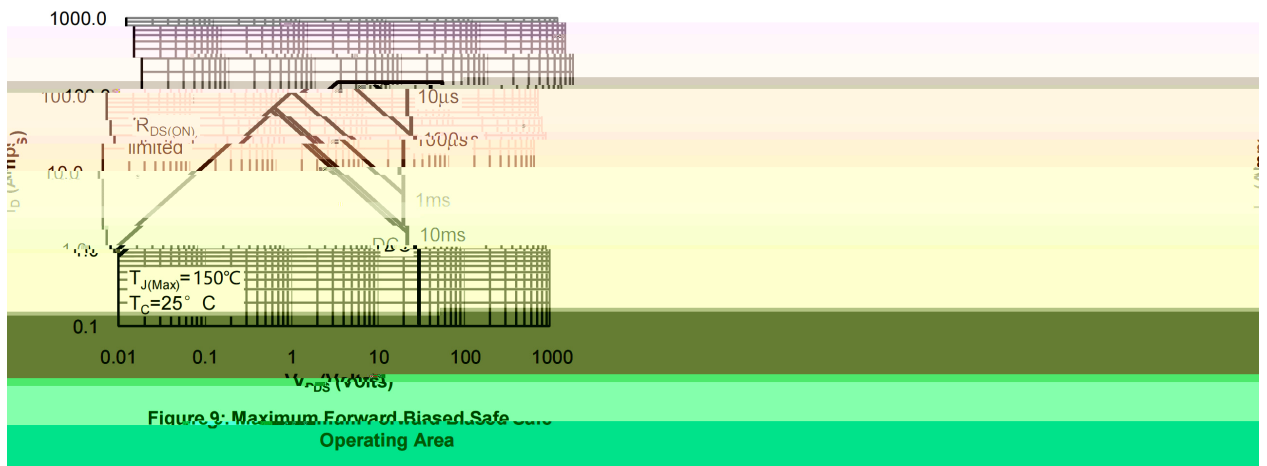
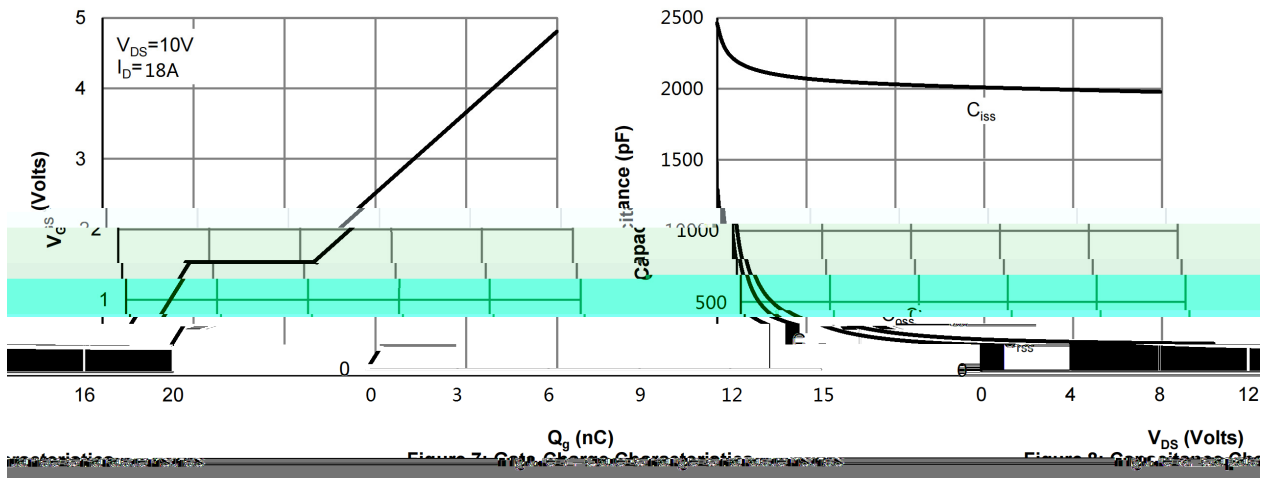
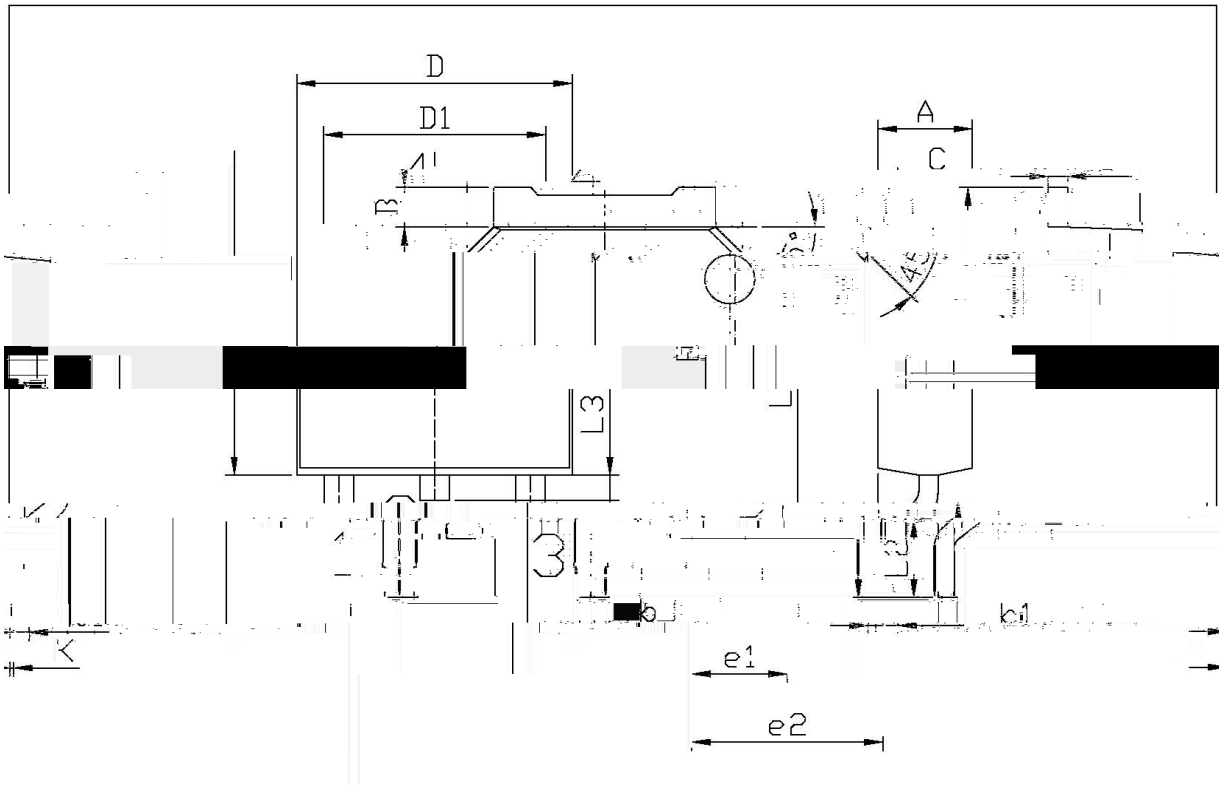


Figure 4: On-Resistance vs. Junction Temperature

Figure 3: On-Resistance vs. Drain Current



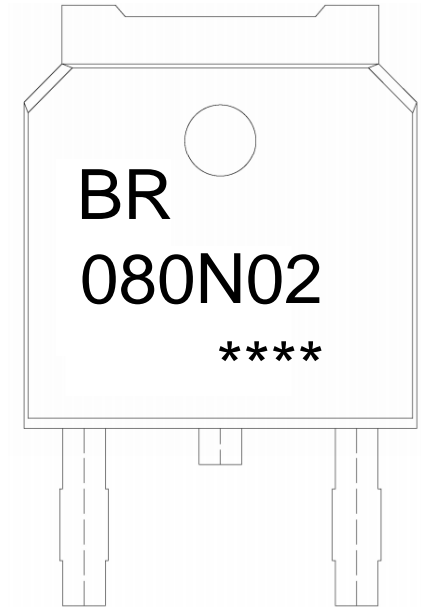




单位: mm

Symbol	Dimensions In Millimeters		Symbol	Dimensions In Millimeters	
	Min	Max		Min	Max
5.95	6.25		A	2.20	2.40
2.24	2.34		B	0.95	1.25
1.35	1.72		b	0.70	0.80
9.85	10.35		b1	0.75	0.55
0.6	0.45	0.55	L3	7.0	7.00
6.75	1.3	0.60	D1	6.45	
0.50	0.4	0.60	K	5.10	

T0-252



BR

080N 02

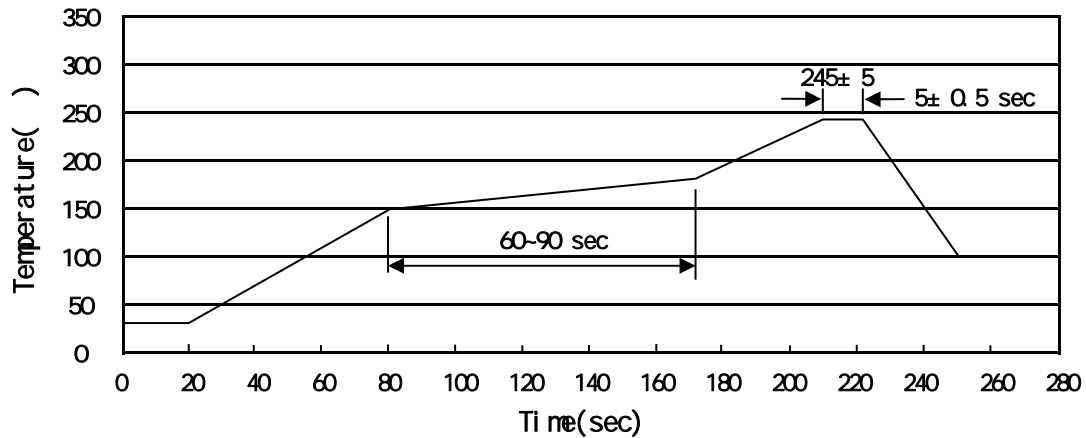
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Note:

BR: Company Code

080N02: Product Type Code

\*\*\*\*: Lot No. Code, code change with Lot No

**Temperature Profile for IR Reflow Soldering(Pb-Free)**


Note:

- |   |       |     |           |        |   |
|---|-------|-----|-----------|--------|---|
| 1 | 150   | 180 | 60        | 90sec; | 1.Preheating:150~180 , Time:60~90sec.   |
| 2 | 245±5 |     | 5±0.5sec; |        | 2.Peak Temp.:245±5 , Duration:5±0.5sec. |
| 3 |       | 2   | 10        | /sec.  | 3. Cooling Speed: 2~10 /sec.            |

260±5

10±1 sec.

Temp.:260±5

Time:10±1 sec

/ REEL

Package Type	Units					Dimension (unit mm <sup>3</sup> )		
	Units/Reel	Reels/Inner Box	Units/Inner Box	Inner Boxes/Outer Box	Units/Outer Box	Reel	Inner Box	Outer Box
TO-252	2,500	2	5,000	6	30,000	13 x16	360x360x50	380x335x366

/ TUBE

Package Type	Units					Dimension (unit mm <sup>3</sup> )		
	Units/Tube	Tubes/Inner Box	Units/Inner Box	Inner Boxes/Outer Box	Units/Outer Box	Tube	Inner Box	Outer Box
TO-251/252	75	48	3,600	5	18,000	526x20.5x5.25	555x164x50	575x290x180